

2N7002BKMB

60 V, single N-channel Trench MOSFET Rev. 2 — 13 June 2012

Product data sheet

1. **Product profile**

1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Very fast switching
- Trench MOSFET technology
- ESD protection up to 2 kV
- Logic-level compatible
- Ultra thin package profile with 0.37 mm height

1.3 Applications

- Relay driver
- High-speed line driver

- Low-side loadswitch
- Switching circuits

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	$V_{GS} = 10 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$	<u>[1]</u>	-	-	450	mA
Static charact	eristics						
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 450 \text{ mA}; T_j = 25 \text{ °C}$		-	1	1.6	Ω

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	S	source	1 3	D
3	D	drain	Transparent top view SOT883B (DFN1006B-3) S 017aaa255

3. Ordering information

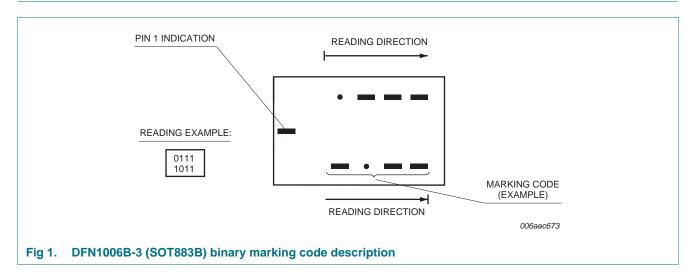
Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
2N7002BKMB	DFN1006B-3	Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm	SOT883B			

4. Marking

Table 4. Marking codes

Type number	Marking code
2N7002BKMB	0000 0001



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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions		Min	Max	Unit
drain-source voltage	T _i = 25 °C		-	60	V
gate-source voltage	_ '		-20	20	V
drain current	V _{GS} = 10 V; T _{amb} = 25 °C	<u>[1]</u>	-	450	mΑ
	V _{GS} = 10 V; T _{amb} = 100 °C	<u>[1]</u>	-	220	mΑ
peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	1.8	Α
total power dissipation	T _{amb} = 25 °C	[2]	-	360	mW
		[1]	-	715	mW
	T _{sp} = 25 °C		-	2700	mW
junction temperature			-55	150	°C
ambient temperature			-55	150	°C
storage temperature			-65	150	°C
diode					
source current	T _{amb} = 25 °C	<u>[1]</u>	-	450	mΑ
n rating					
electrostatic discharge voltage	НВМ	[3]	-	2000	V
	drain-source voltage gate-source voltage drain current peak drain current total power dissipation junction temperature ambient temperature storage temperature diode source current rating	$ \begin{array}{lll} drain\text{-source voltage} & T_j = 25 \ ^{\circ}\text{C} \\ gate\text{-source voltage} \\ drain current & V_{GS} = 10 \ ^{\circ}\text{C}, \ T_{amb} = 25 \ ^{\circ}\text{C} \\ V_{GS} = 10 \ ^{\circ}\text{C}, \ T_{amb} = 100 \ ^{\circ}\text{C} \\ \end{array} $ $ \begin{array}{ll} peak \ drain \ current & T_{amb} = 25 \ ^{\circ}\text{C}; \ single \ pulse; \ t_p \leq 10 \ \mu s \\ \hline total \ power \ dissipation & T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline T_{sp} = 25 \ ^{\circ}\text{C} \\ \hline junction \ temperature & \\ ambient \ temperature & \\ storage \ temperature & \\ \hline storage \ temperature & \\ \hline source \ current & T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline rating & \end{array} $	$ \begin{array}{c} drain\text{-source voltage} \\ gate\text{-source voltage} \\ drain current \\ \hline \\ V_{GS} = 10 \text{ V}; T_{amb} = 25 \text{ °C} \\ \hline \\ V_{GS} = 10 \text{ V}; T_{amb} = 100 \text{ °C} \\ \hline \\ 11 \\ \hline \\ peak drain current \\ \hline \\ total power dissipation \\ \hline \\ T_{amb} = 25 \text{ °C}; single pulse; t_p \leq 10 \mu s \\ \hline \\ total power dissipation \\ \hline \\ T_{amb} = 25 \text{ °C} \\ \hline \\ 11 \\ \hline \\ T_{sp} = 25 \text{ °C} \\ \hline \\ junction temperature \\ ambient temperature \\ storage temperature \\ \hline \\ storage temperature \\ \hline \\ source current \\ \hline \\ T_{amb} = 25 \text{ °C} \\ \hline \\ \hline \\ 11 \\ \hline \\ T_{amb} = 25 \text{ °C} \\ \hline \\ \hline \\ 11 \\ \hline \\ \hline \\ 11 \\ \hline \\ 12 \\ \hline \\ \hline \\ 13 \\ \hline \\ 14 \\ \hline \\ 14 \\ \hline \\ 15 \\ \hline \\ 15 \\ \hline \\ 15 \\ \hline \\ 16 \\ \hline \\ 17 \\ \hline \\ 17 \\ \hline \\ 17 \\ \hline \\ 17 \\ \hline \\ 18 \\ \hline \\ 18 \\ \hline \\ 19 \\ \hline \\ 19 \\ \hline \\ 10 \\ \hline \\ 10 \\ \hline \\ 10 \\ \hline \\ 10 \\ \hline \\ 11 \\ \hline \\ 10 \\ \hline \\ 11 \\ \hline \\ 11 \\ \hline \\ 11 \\ \hline \\ 12 \\ \hline \\ 12 \\ \hline \\ 13 \\ \hline \\ 14 \\ \hline \\ 15 \\ \hline \\ 15$	$ \begin{array}{c} drain\text{-source voltage} \\ gate\text{-source voltage} \\ \\ drain current \\ \hline \\ V_{GS} = 10 \text{ V}; T_{amb} = 25 ^{\circ}\text{C} \\ \hline \\ V_{GS} = 10 \text{ V}; T_{amb} = 100 ^{\circ}\text{C} \\ \hline \\ 11 \\ \hline \\ V_{GS} = 10 \text{ V}; T_{amb} = 100 ^{\circ}\text{C} \\ \hline \\ 11 \\ \hline \\ 11 \\ \hline \\ T_{amb} = 25 ^{\circ}\text{C}; single pulse; t_p \leq 10 \mus \\ \hline \\ total power dissipation \\ \hline \\ T_{amb} = 25 ^{\circ}\text{C} \\ \hline \\ 11 \\ \hline \\ T_{sp} = 25 ^{\circ}\text{C} \\ \hline \\ junction temperature \\ \hline \\ ambient temperature \\ \hline \\ storage temperature \\ \hline \\ source current \\ \hline \\ T_{amb} = 25 ^{\circ}\text{C} \\ \hline \\ T_{amb} = 25 ^{\circ}\text{C} \\ \hline \\ \hline \\ T_{amb} = 25 ^{\circ}\text{C} \\ \hline \\ $	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Measured between all pins.

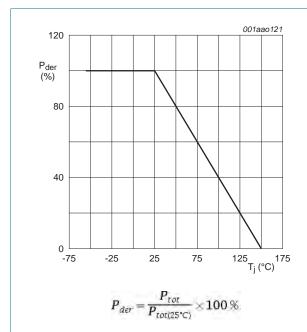


Fig 2. Normalized total power dissipation as a function of junction temperature

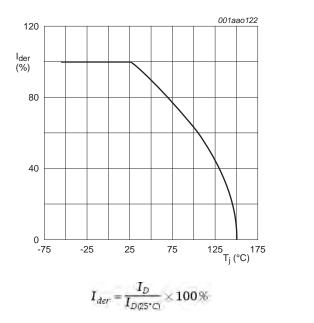
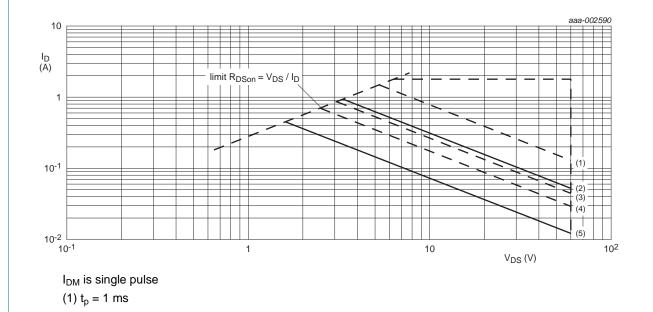


Fig 3. Normalized continuous drain current as a function of junction temperature

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- (2) DC; $T_{sp} = 25 \, ^{\circ}\text{C}$
- (3) $t_p = 10 \text{ ms}$
- (4) $t_p = 100 \text{ ms}$
- (5) DC; $T_{amb} = 25 \text{ °C}$; drain mounting pad 1 cm²

Fig 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance	in free air [1]	<u>[1]</u>	-	305	350	K/W
	from junction to ambient		[2]	-	150	175	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	40	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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4 of 15

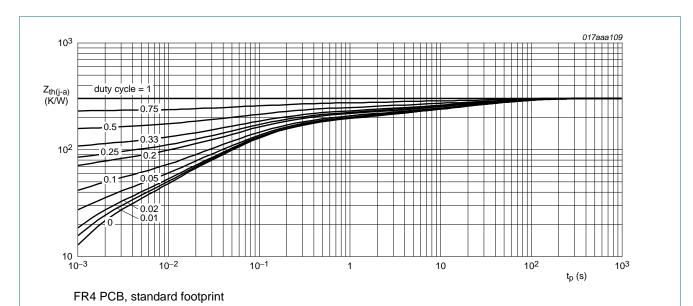


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

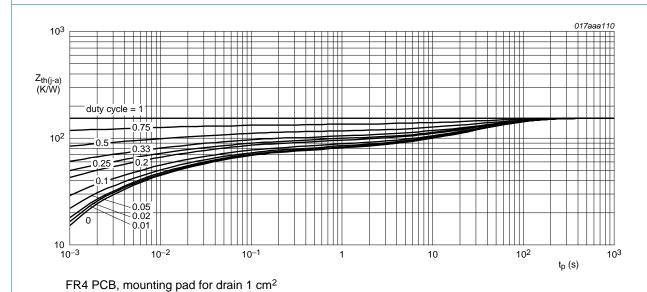


Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

7. Characteristics

Table 7. Characteristics

Table 1.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 10 \mu A; V_{GS} = 0 V; T_j = 25 °C$	60	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.1	1.6	2.1	V
I _{DSS}	drain leakage current	$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μΑ
		$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	10	μΑ
I _{GSS}	gate leakage current	$V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	10	μΑ
		$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	10	μΑ
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 450 \text{ mA}; T_j = 25 \text{ °C}$	-	1	1.6	Ω
		$V_{GS} = 10 \text{ V}; I_D = 450 \text{ mA}; T_j = 150 \text{ °C}$	-	2.2	3.5	Ω
		V_{GS} = 5 V; I_D = 50 mA; T_j = 25 °C	-	1.3	2	Ω
9 _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 200 \text{ mA}; T_j = 25 \text{ °C}$	-	550	-	mS
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	$V_{DS} = 30 \text{ V}; I_D = 300 \text{ mA}; V_{GS} = 4.5 \text{ V};$	-	0.5	0.6	nC
Q_{GS}	gate-source charge	T _j = 25 °C	-	0.2	-	nC
Q_{GD}	gate-drain charge		-	0.1	-	nC
C _{iss}	input capacitance	$V_{DS} = 10 \text{ V}; f = 1 \text{ MHz}; V_{GS} = 0 \text{ V};$	-	33	50	pF
Coss	output capacitance	T _j = 25 °C	-	7	-	pF
C _{rss}	reverse transfer capacitance		-	4	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 50 V; R_L = 250 Ω ; V_{GS} = 10 V;	-	5	10	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 $ °C	-	6	-	ns
t _{d(off)}	turn-off delay time		-	12	24	ns
t _f	fall time		-	7	-	ns
Source-d	rain diode					
V_{SD}	source-drain voltage	$I_S = 115 \text{ mA}; V_{GS} = 0 \text{ V}; T_i = 25 \text{ °C}$	0.47	0.75	1.1	V

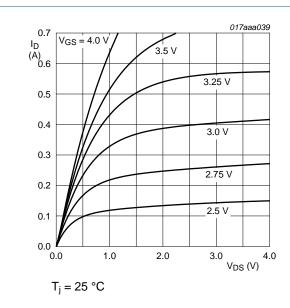
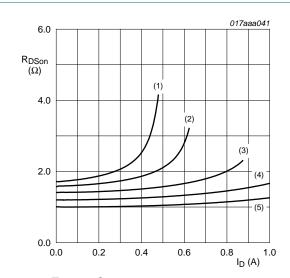


Fig 7. Output characteristics: drain current as a function of drain-source voltage; typical values



 $T_i = 25 \, ^{\circ}C$

(1) $V_{GS} = 3.25 \text{ V}$

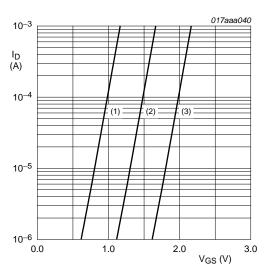
(2) $V_{GS} = 3.5 \text{ V}$

(3) $V_{GS} = 4 V$

(4) $V_{GS} = 5 \text{ V}$

(5) $V_{GS} = 10 \text{ V}$

Fig 9. Drain-source on-state resistance as a function of drain current; typical values



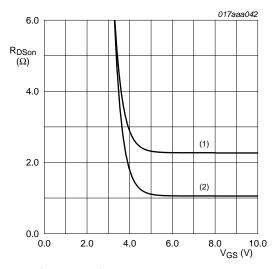
 $T_j = 25 \, ^{\circ}C; \, V_{DS} = 5 \, V$

(1) minimum values

(2) typical values

(3) maximum values

Fig 8. Sub-threshold drain current as a function of gate-source voltage



 $I_D = 500 \text{ mA}$

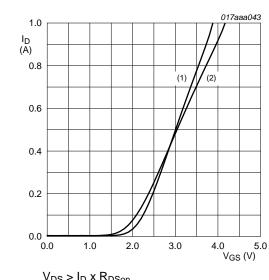
(1) $T_i = 150 \, ^{\circ}C$

(2) $T_j = 25 \, ^{\circ}C$

Fig 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

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 $V_{DS} > I_D \times R_{DSon}$

(1)
$$T_j = 25 \, ^{\circ}C$$

(2)
$$T_i = 150 \, ^{\circ}\text{C}$$

Fig 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

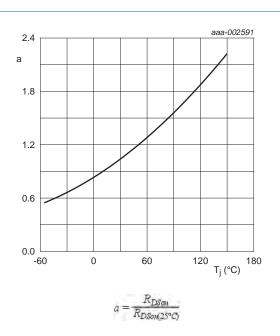
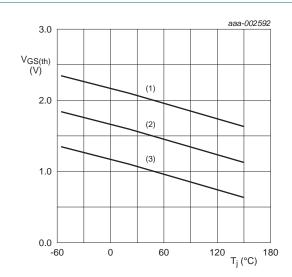


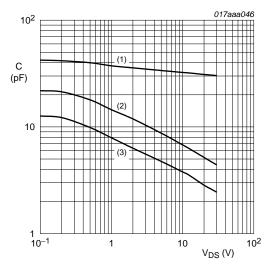
Fig 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values



 $I_D = 0.25 A; V_{DS} = V_{GS}$

- (1) maximum values
- (2) typical values
- (3) minimum values

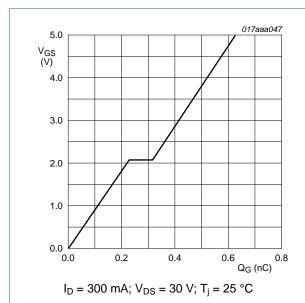
Fig 13. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

- (1) C_{iss}
- (2) C_{oss}
- (3) C_{rss}

Fig 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



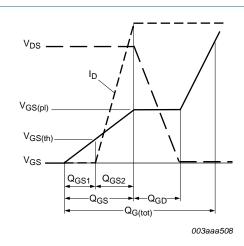
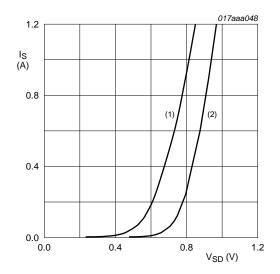


Fig 15. Gate-source voltage as a function of gate charge; typical values

Fig 16. Gate charge waveform definitions



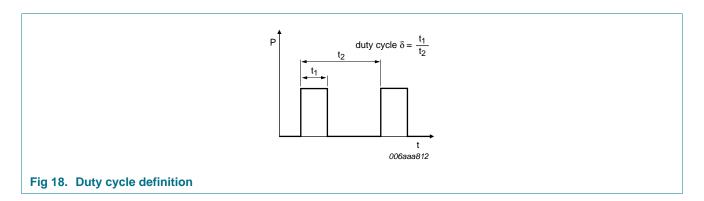
 $V_{GS} = 0 V$

(1) $T_j = 150 \, ^{\circ}\text{C}$

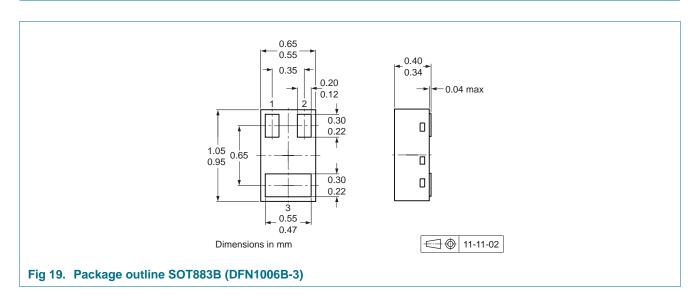
(2) $T_j = 25 \, ^{\circ}C$

Fig 17. Source current as a function of source-drain voltage; typical values

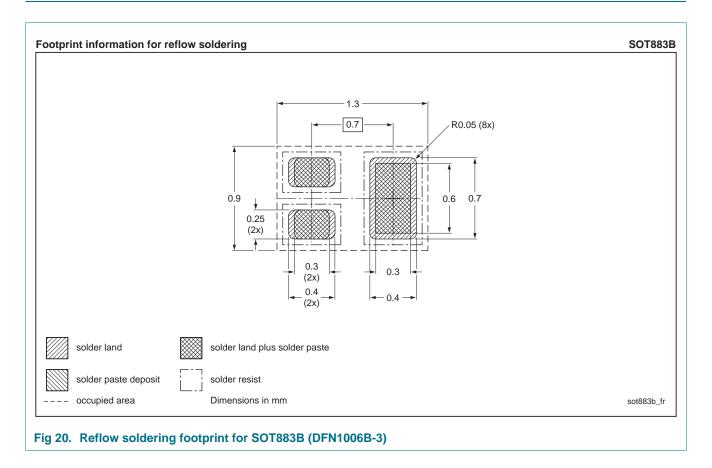
8. Test information



9. Package outline



10. Soldering



11. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
2N7002BKMB v.2	20120613	Product data sheet	-	2N7002BKMB v.1
Modifications:	 7 "Characteri 	stics": R _{DSon} condition correc	cted	
2N7002BKMB v.1	20120511	Product data sheet	-	-

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12.1 Data sheet status

Document status[1] [2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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60 V, single N-channel Trench MOSFET

14. Contents

1	Product profile	.1
1.1	General description	.1
1.2	Features and benefits	.1
1.3	Applications	.1
1.4	Quick reference data	.1
2	Pinning information	.2
3	Ordering information	.2
4	Marking	.2
5	Limiting values	.3
6	Thermal characteristics	.4
7	Characteristics	.6
8	Test information	10
9	Package outline	10
10	Soldering	11
11	Revision history	12
12	Legal information	13
12.1	Data sheet status	13
12.2	Definitions	13
12.3	Disclaimers	13
12.4	Trademarks	14
13	Contact information	14

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